

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Norikatsu Koide et al.

Serial No.: 09/711,908

Group Art Unit: 2814

Filed: November 15, 2000

Examiner: Louie, Wai Sing

For: METHODS FOR MANUFACTURING A LIGHT-EMITTING DEVICE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

REQUEST FOR CONSIDERATION OF
INFORMATION DISCLOSURE STATEMENT

Sir:

Applicant respectfully requests that the Information Disclosure Statement submitted and filed on November 15, 2000, be officially considered of record. Attached is a copy of the Form PTO-1449 filed on November 15, 2000, as well as a copy of the date-stamped postcard. Applicant respectfully requests that the Examiner officially acknowledge the disclosed information and promptly return the initialed Form PTO-1449.

Respectfully submitted,

Dated: 12/11/03

Peter A. Balnave
Peter A. Balnave
Reg. No. 46,199

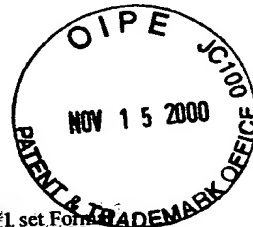
McGinn & Gibb, PLLC
8321 Old Courthouse Road
Suite 200
Vienna, Virginia 22182-3817
(703) 761-4100
Customer Number: 21254



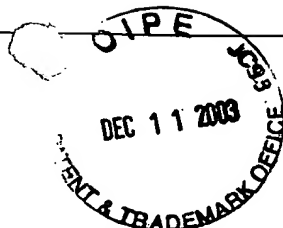
PAT-103-8/99 PTO REC INDICATED ITEMS Atty. PWG/GRT
Appln. No: 0 / Date 11/15/2000
Inventor(s): KOIDE et al. CH# 51273
Title: Methods for Manufacturing a Light-Emitting Device M# 268415

ENCLOSED:

- ☒ Preliminary Amendment
- ☐ No. of Pages Abstract
- # 17 No. of Pages Spec and Claims
- # 12 No. of numbered Claims only
- ☒ Declaration (2 #pgs)
- ☒ Assignment ☒ Cover Sheet
- # No. of Priority Documents
- # 2 No. Sheets Drawings (Fig(s) 1 to 2+) ☒ 1 set Form
- ☐ IDS Letter ☐ citing App: ☐ Foreign sch rept/OA
- ☒ PTO-1449 ☐ cited docs.
- \$ 750.00 Fee (Check)
- Other:



CURRENT DUE DATE: November 15, 2000



| | | |
|-------------------|--------|------------------|
| Atty. Dkt. No. | M# | Cl. nt Ref. |
| | 268415 | T36-127889 M/KOH |

**INFORMATION DISCLOSURE STATEMENT
BY APPLICANT**

| | |
|---|----------------------|
| Applicant: KOIDE et al. | |
| Appln. No.: Continuation of Appln. No. 08/925,323 | |
| Filing Date: November 15, 2000 | |
| Examiner: J. JACKSON | Group Art Unit: 2815 |

Date: November 15, 2000

Page 1 of 1

U.S. PATENT DOCUMENTS

| Examiner's Initials* | Document Number | Date MM/YYYY | Name (Family Name of First Inventor) | Class | Sub Class | Filing Date (if appropriate) |
|-------------------------|--------------------|-----------------|---|-------|--------------|------------------------------------|
| | AR 5,929,466 | 07/1999 | OHBA | | | |
| | BR 5,877,558 | 03/1999 | NAKAMURA et al. | | | |
| | CR 5,760,945 | 06/1998 | COLEMAN | | | |
| | DR 5,656,823 | 08/1997 | KRUANGAM | | | |
| | ER 5,502,316 | 03/1996 | KISH et al. | | | |
| | FR 5,466,950 | 11/1995 | SUGAWARA et al. | | | |
| | GR 5,641,682 | 06/1997 | NIRE et al. | | | |
| | HR 5,592,501 | 01/1997 | EDMOND et al. | | | |
| | IR | | | | | |
| | JR | | | | | |
| | KR | | | | | |
| | LR | | | | | |
| | MR | | | | | |
| | NR | | | | | |

FOREIGN PATENT DOCUMENTS

| | | Document Number | Date MM/YYYY | Country | Inventor Name | | English Abstract | | Translation Readily Available | |
|--|----|--------------------|-----------------|---------|---------------|--|---------------------|----|-------------------------------------|----|
| | | | | | | | Enclosed | No | Enclos | No |
| | OR | | | | | | | | | |
| | PR | | | | | | | | | |
| | QR | | | | | | | | | |
| | RR | | | | | | | | | |
| | SR | | | | | | | | | |
| | TR | | | | | | | | | |
| | UR | | | | | | | | | |

OTHER (Including in this order Author, Title, Periodical Name, Date, Pertinent Pages, etc.)

| | | | | |
|-----|---|--|--|--|
| VR | Nakamura, "Growth of $\text{In}_x\text{Ga}_{1-x}\text{N}$ Compound Semiconductors and High-Power InGaN/AlGaN Double Heterostructure Violet-Light-Emitting Diodes," Microelectronics Journal, 1994, Vol. 25, pp. 651-659 | | | |
| WR | Osamura et al., "Preparation and Optical Properties of $\text{Ga}_{1-x}\text{In}_x\text{N}$ Thin Films," Journal of Applied Physics, August 1975, Vol. 46, No. 8, pp. 3432-3437 | | | |
| XR | Nakamura et al., "P-GaN/N-InGaN/N-GaN Double-Heterostructure Blue-Light-Emitting Diodes," Japanese Journal of Applied Physics, 1993, Vol. 32, pp. L8-L11 | | | |
| YR | | | | |
| ZR | | | | |
| AAR | | | | |

| | |
|--|------------------|
| Examiner | Date Considered: |
| *EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant. | |